



(

! M

M . HH M

KK® DI

JG (DI H DB



(

G ND G C M ND D

MH M	JI DDI	. H JG	1 G			0 I D
			(D	K	(	
	°C					
	°C					
	°C					
	°C					

C NH G C M ND D

MH M	JI DDI	. H JG	1 G			0 I D
			(D	K	(	

M ND B I ANH DI

D	(MFB	F B	2 BC	I I M J	M MJI



(

KD G G MD G C MH G C M MD D

FIG.1: Forward characteristics(per diode)

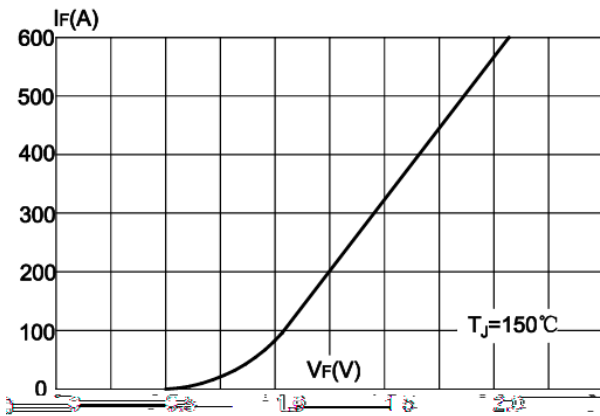


FIG.2: Peak on-state surge current

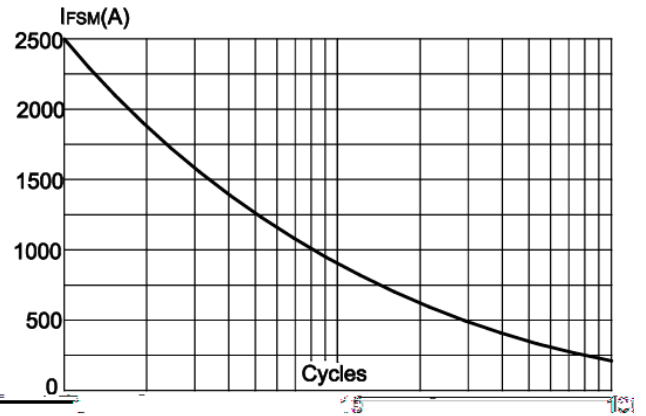


FIG.3: Forward current vs. case temperature

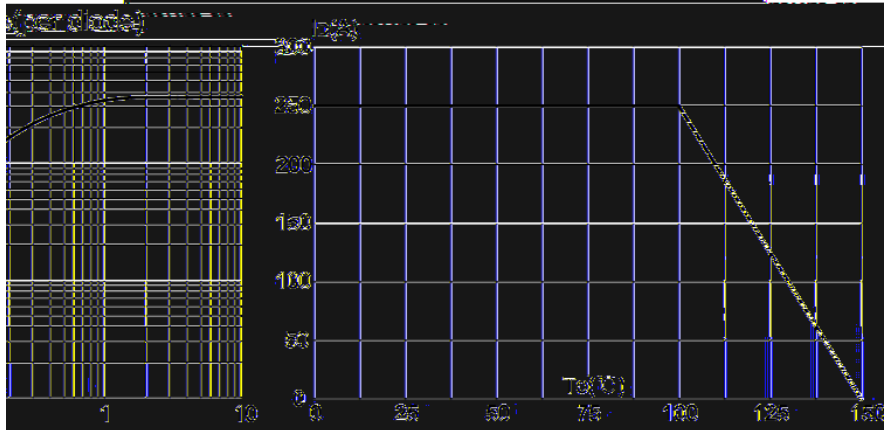
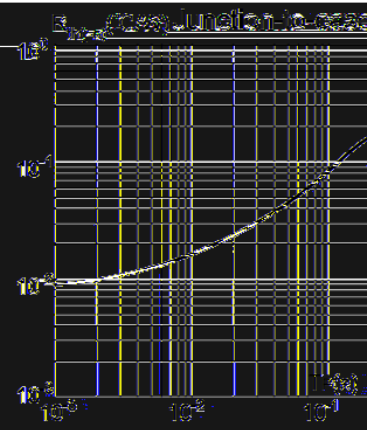
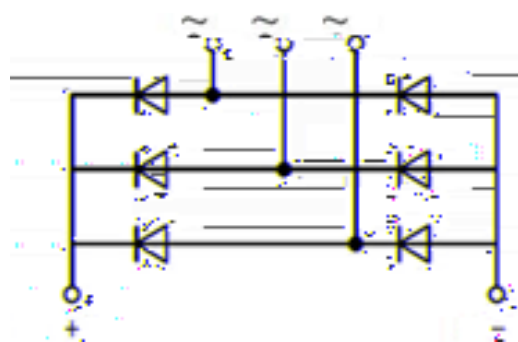


FIG.4: Maximum transient thermal impedance



DM D DBMH



MIN 1.2

3

30±0.75

M6(5X)

52±0.5

12

6.5

Ø6.5

54±0.75

27±0.5

1

2

3

4

5

6

25±0.5

72

80±0.5

94±0.75



(